
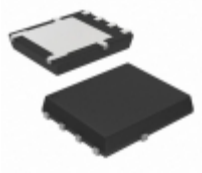
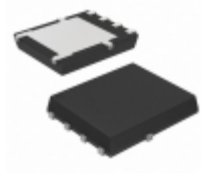
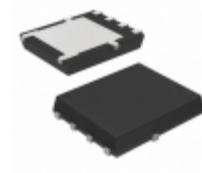
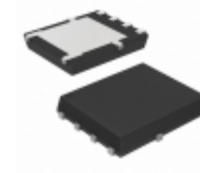
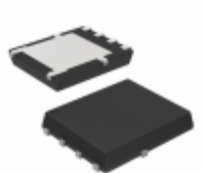
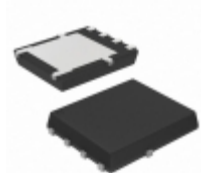
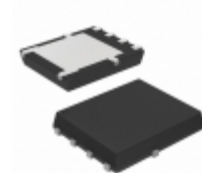
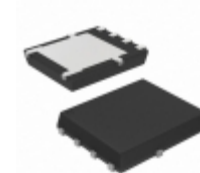
	<p>NVMFS5885NLT3G</p>
	<p>Hersteller-Teilenummer: NVMFS5885NLT3G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 39A SO8FL</p> <p>Datenblätter:  NVMFS5885NLT3G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 929 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NVMFS5885NLT3G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 39A SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	929 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Verlustleistung (max)	3.7W (Ta), 54W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	10.2A (Ta)
Rds On (Max) @ Id, Vgs	15 mOhm @ 15A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	21nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1340pF @ 25V
Verpackung	Tape & Reel (TR)





















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Sie können auch interessiert sein:

 <p>NVMFS5844NLT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 8SOIC</p>	 <p>NVMFS5885NLWFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 39A SO8FL</p>	 <p>NVMFS5885NLWFT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 39A SO8FL</p>	 <p>NVMFS5844NLWFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 61A SO8FL</p>
 <p>NVMFS5A140PLZT3G AMI Semiconductor / ON Semiconductor -40V4.2MOHMSINGLE</p>	 <p>NVMFS5A140PLZWFT1G AMI Semiconductor / ON Semiconductor -40V4.2MOHMSINGLE</p>	 <p>NVMFS5885NLT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 39A SO8FL</p>	 <p>NVMFS5844NLWFT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 61A SO8FL</p>

heiße Teile

Mehr

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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